

NP60N04VDK

40 V – 60 A – N-channel Power MOS FET Application: Automotive

R07DS1014EJ0200 Rev.2.00 May 24, 2018

Description

The NP60N04VDK is N-channel MOS Field Effect Transistors designed for high current switching applications.

Features

- Super low on-state resistance $R_{DS(on)} = 3.85 \text{ m}\Omega \text{ MAX.} (V_{GS} = 10 \text{ V}, I_D = 30 \text{ A})$
- Low C_{iss} : $C_{iss} = 2450 \text{ pF TYP.} (V_{DS} = 25 \text{ V})$
- Logic level drive type
- Designed for automotive application and AEC-Q101 qualified

Ordering Information

Part No.	Lead Plating	Packing		Package
NP60N04VDK-E1-AY *1	Pure Sn (Tin)	Tape 2500 p/reel	Taping (E1 type)	TO-252 (MP-3ZP)
NP60N04VDK-E2-AY *1			Taping (E2 type)	

Note: *1 Pb-free (This product does not contain Pb in the external electrode)

Absolute Maximum Ratings $(T_A = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to Source Voltage (V _{GS} = 0 V)	V _{DSS}	40	V
Gate to Source Voltage (V _{DS} = 0 V)	V _{GSS}	±20	V
Drain Current (DC) (T _C = 25°C)	I _{D(DC)}	±60	Α
Drain Current (pulse) *1, 3	I _{D(pulse)}	±240	Α
Total Power Dissipation (T _C = 25°C)	P _{T1}	105	W
Total Power Dissipation (T _A = 25°C)	P _{T2}	1.2	W
Channel Temperature	T _{ch}	175	°C
Storage Temperature	T _{stg}	-55 to +175	°C
Repetitive Avalanche Current *2, 3	I _{AR}	28	Α
Repetitive Avalanche Energy *2, 3	Ear	78	mJ

Thermal Resistance

Notes: *1 T_C = 25°C, $P_W \le 10 \mu s$, Duty Cycle $\le 1\%$

*2 R_G = 25 Ω , V_{GS} = 20 V \rightarrow 0 V

*3. Not subject of production test. Verified by design/characterization.

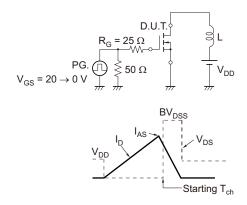
Electrical Characteristics (T_A = 25°C)

Item	Symbol	MIN.	TYP.	MAX.	Unit	Test Conditions	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	1	μΑ	V _{DS} = 40 V, V _{GS} = 0 V	
Gate Leakage Current	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$	
Gate to Source Threshold Voltage	$V_{GS(th)}$	1.5	1.8	2.5	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Forward Transfer Admittance *1	yfs	33	66	_	S	$V_{DS} = 5 \text{ V}, I_{D} = 30 \text{ A}$	
Drain to Source On-state Resistance *1	R _{DS(on)1}	_	3.20	3.85	mΩ	$V_{GS} = 10 \text{ V}, I_D = 30 \text{ A}$	
	R _{DS(on)2}	_	4.30	8.60	mΩ	$V_{GS} = 4.5 \text{ V}, I_D = 15 \text{ A}$	
Input Capacitance *2	C _{iss}	_	2450	3680	pF	V _{DS} = 25 V	
Output Capacitance *2	Coss	_	340	510	pF	$V_{GS} = 0 V$	
Reverse Transfer Capacitance *2	C _{rss}	_	140	260	pF	f = 1 MHz	
Turn-on Delay Time *2	t _{d(on)}	_	14	31	ns	$V_{DD} = 20 \text{ V}, I_D = 30 \text{ A}$	
Rise Time *2	t _r	_	6	15	ns	V _{GS} = 10 V	
Turn-off Delay Time *2	t _{d(off)}	_	49	98	ns	$R_G = 0 \Omega$	
Fall Time *2	t _f	_	6	15	ns		
Total Gate Charge *2	Q_G	_	42	63	nC	V _{DD} = 32 V	
Gate to Source Charge	Q _{GS}	_	11	_	nC	V _{GS} = 10 V	
Gate to Drain Charge	Q _{GD}	_	6	_	nC	I _D = 60 A	
Body Diode Forward Voltage *1	V _{F(S-D)}	_	0.9	1.5	V	I _F = 60 A, V _{GS} = 0 V	
Reverse Recovery Time	t _{rr}	_	36	_	ns	I _F = 60 A, V _{GS} = 0 V	
Reverse Recovery Charge	Qrr	_	44	_	nC	di/dt = 100 A/μs	

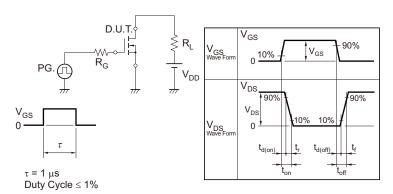
Note: *1 Pulsed test

Note: *2 Not subject of production test. Verified by design/characterization.

TEST CIRCUIT 1 AVALANCHE CAPABILITY



TEST CIRCUIT 2 SWITCHING TIME

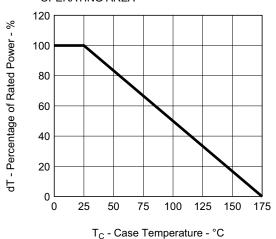


TEST CIRCUIT 3 GATE CHARGE

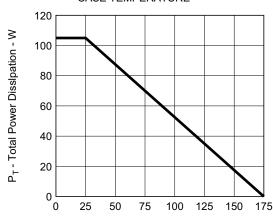
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Typical Characteristics (T_A = 25°C)

DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA

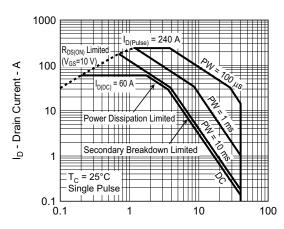


TOTAL POWER DISSIPATION vs. CASE TEMPERATURE



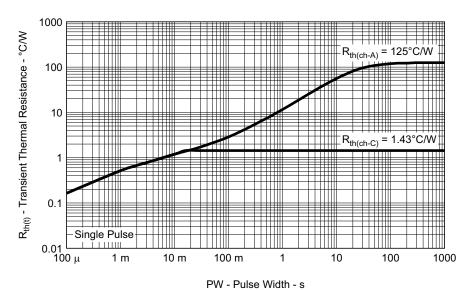
T_C - Case Temperature - °C

FORWARD BIAS SAFE OPERATING AREA



 V_{DS} - Drain to Source Voltage - V

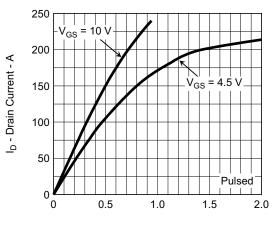
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



V_{GS(th)} - Gate to Source Threshold Voltage - V

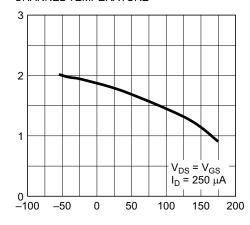
 $R_{DS(on)}$ - Drain to Source On-State Resistance - $m\Omega$

DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



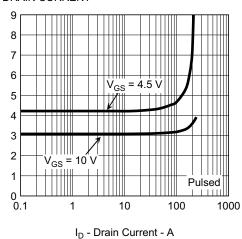
 V_{DS} - Drain to Source Voltage - V

GATE TO SOURCE THRESHOLD VOLTAGE vs. CHANNEL TEMPERATURE

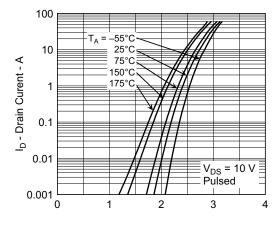


T_{ch} - Channel Temperature - °C

DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT

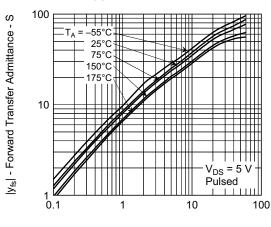


FORWARD TRANSFER CHARACTERISTICS



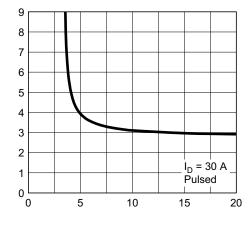
 V_{GS} - Gate to Source Voltage - V

FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



I_D - Drain Current - A

DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE

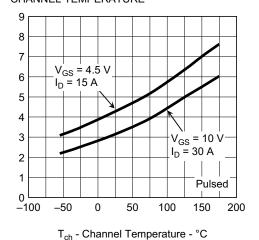


 V_{GS} - Gate to Source Voltage - V

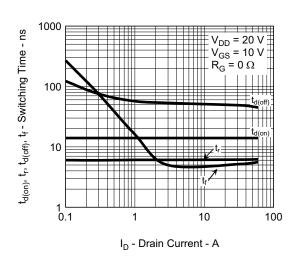
 $R_{DS(on)}$ - Drain to Source On-State Resistance - $m\Omega$

 $\mathsf{R}_{\mathsf{DS}(\mathsf{on})}$ - Drain to Source On-State Resistance - $m\Omega$

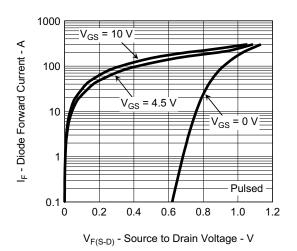
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



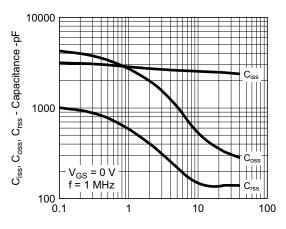
SWITCHING CHARACTERISTICS



SOURCE TO DRAIN DIODE FORWARD VOLTAGE

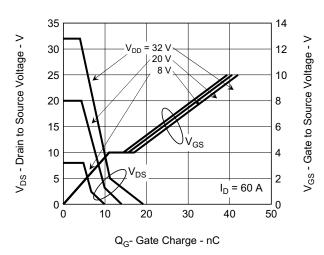


CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE

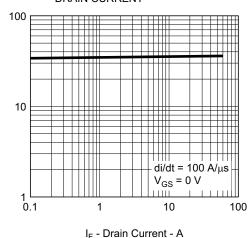


V_{DS} - Drain to Source Voltage - V

DYNAMIC INPUT/OUTPUT CHARACTERISTICS



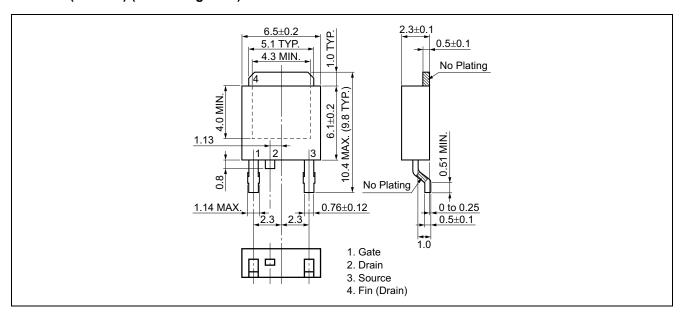
REVERSE RECOVERY TIME vs. DRAIN CURRENT



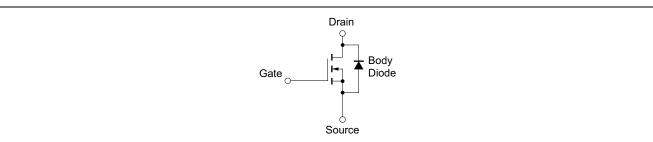
t_{rr} - Reverse Recovery Time - ns

Package Drawing (Unit: mm)

TO-252 (MP-3ZP) (Mass: 0.3g TYP.)



Equivalent Circuit



Remark: Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

Revision History

NP60N04VDK Data Sheet

		Description		
Rev.	Date	Page	Summary	
1.00	Feb 21, 2013	_	First Edition Issued	
2.00	May 24 ,2018	1	Note 3 was added	
		2	Note 2 was added	

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